



40V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	Rds(on) max	I _{D MAX} T _A = +25°C
-40V	51mΩ @ V _{GS} = -10V	-10.5A
	85mΩ @ V _{GS} = -4.5V	-8.4A

Description and Applications

This MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- DC-DC Converters
- · Power Management Functions

Features and Benefits

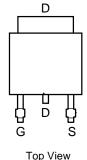
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- · Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

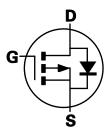
- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.33 grams (Approximate)



Top View



Pin-Out



Equivalent Circuit

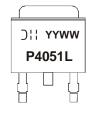
Ordering Information (Notes 4 and 5)

Product	Grade	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DMP4051LK3-13	Commercial	P4051L	13	16	2,500
DMP4051LK3Q-13	Automotive	P4051L	13	16	2,500

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



⊃¹¹ = Manufacturer's Marking
 P4051L = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Year (ex: 18 = 2018)
 WW = Week (01 to 53)



Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-40	V
Gate-Source Voltage		(Note 6)	V _{GS}	±20	V
Single Pulsed Avalanche Er	nergy	(Note 12)	E _{AS}	50	mJ
Single Pulsed Avalanche Current (Note 12)		(Note 12)	I _{AS}	-20.3	A
		(Note 8)		-10.5	
Continuous Drain Current	V _{GS} = -10V	$T_A = +70^{\circ}C \text{ (Note 8)}$	lo	-8.40	Α
		(Note 7)		-7.2	
Pulsed Drain Current $V_{GS} = -10V$ (Note 9)		(Note 9)	I _{DM}	-28.9	Α
Continuous Source Current (Body Diode) (Note 8)		I _S	-10.1	Α	
Pulsed Source Current (Body Diode) (Note 8)		I _{SM}	-28.9	А	

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
	(Note 7)		4.18 33.4	
Power Dissipation Linear Derating Factor	(Note 8)	P _D	8.9 71.4	W mW/°C
	(Note 10)		2.14 17.1	
	(Note 7)		29.9	
Thermal Resistance, Junction to Ambient	(Note 8)	$R_{\theta JA}$	14.0	0000
	(Note 10)		58.4	°C/W
Thermal Resistance, Junction to Lead	(Note 11)	$R_{ heta JL}$	2.46	
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Notes:

- 6. AEC-Q101 V_{GS} maximum is ±16V.
- 7. For a device surface mounted on 50mm x 50mm x 1.6mm FR-4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 8. Same as note 7, except the device is measured at $t \le 10s$.
- 9. Same as note 7, except the device is pulsed with D = 0.02 and pulse width 300µs. The pulse current is limited by the maximum junction temperature.

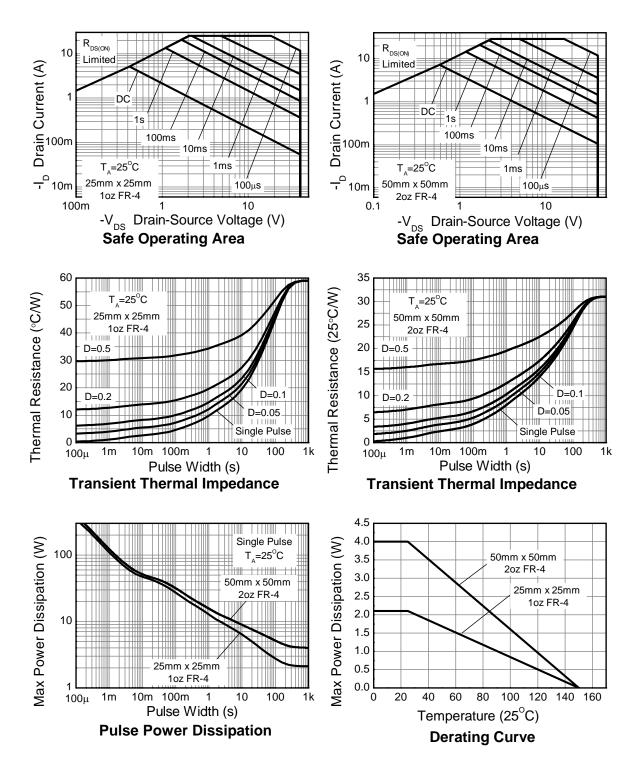
 10. For a device surface mounted on 25mm x 25mm x 1.6mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is
- measured when operating in a steady-state condition.

 11. Thermal resistance from junction to solder-point (at the end of the drain lead).

 12. UIS in production with L = 100μH, V_{DD} = -40V.



Thermal Characteristics





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

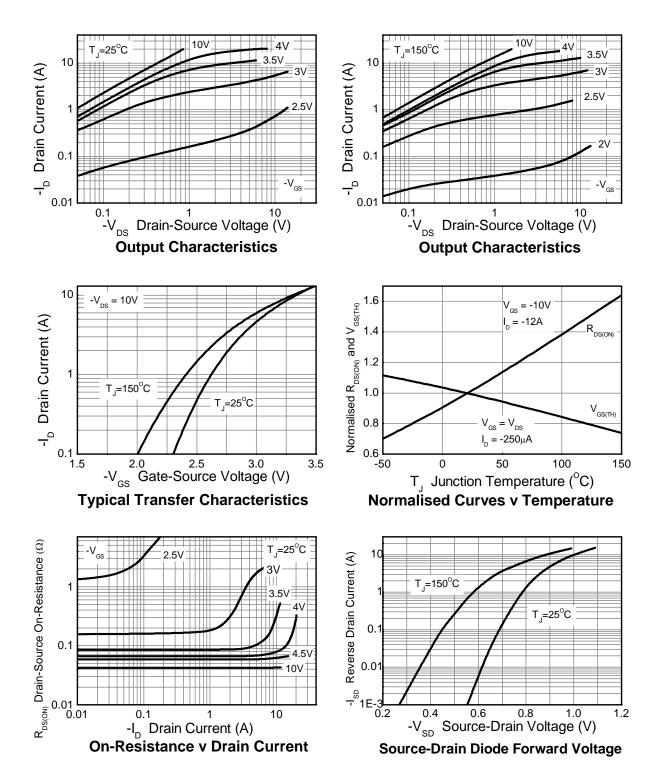
Characteristic	Symbol	Min	Тур	Max	Unit	Test Co	ondition
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV_{DSS}	-40	_	_	V	$I_D = -250 \mu A, V_{GS}$	V0 = 2
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-0.5	μΑ	$V_{DS} = -40V, V_{GS}$	= 0V
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS}$	S = 0V
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(TH)}	-1.0	_	-3.0	V	$I_D = -250 \mu A, V_{DS}$	$s = V_{GS}$
Static Drain Source On Decistores (Note 14)			0.041	0.051	Ω	$V_{GS} = -10V, I_{D} =$	-12A
Static Drain-Source On-Resistance (Note 14)	R _{DS(ON)}		0.059	0.085	77	$V_{GS} = -4.5V, I_D =$	= -8A
Forward Transconductance (Notes 13 & 14)	g fs		16.6	_	S	$V_{DS} = -15V, I_{D} =$	-12A
Diode Forward Voltage (Note 13)	V_{SD}	_	-0.98	-1.2	V	I _S = -12A, V _{GS} =	0V
Reverse Recovery Time (Note 14)	t _{rr}		138		ns	I _S = -12A, di/dt = 100A/μs	
Reverse Recovery Charge (Note 13)	Q_{rr}	_	841	_	nC		
DYNAMIC CHARACTERISTICS (Note 14)							
Input Capacitance	C _{ISS}		674	_	pF	V _{DS} = -20V, V _{GS} = 0V f = 1MHz	
Output Capacitance	Coss		115	_	рF		
Reverse Transfer Capacitance	C _{RSS}	_	67.7	_	pF	71 = 1101112	
Total Gate Charge (Note 15)	Q_G	_	7.0	_	nC	$V_{GS} = -4.5V$	
Total Gate Charge (Note 15)	Q_G	_	14	_	nC		$V_{DS} = -20V$
Gate-Source Charge (Note 15)	Q_{GS}	_	2.2	_	nC	V _{GS} = -10V	
Gate-Drain Charge (Note 15)	Q_GD	_	3.7	_	nC		
Turn-On Delay Time (Note 15)	t _{d(on)}	_	2.3	_	ns	V_{DD} = -20V, V_{GS} = -10V I_{D} = -12A, $R_{G} \approx 6.0\Omega$	
Turn-On Rise Time (Note 15)	t _r		14.1	_	ns		
Turn-Off Delay Time (Note 15)	t _{d(off)}		25.1	_	ns		
Turn-Off Fall Time (Note 15)	t _f		14.3	_	ns		

Notes:

- 13. Measured under pulsed conditions. Pulse width $\leq 300 \mu s;$ duty cycle $\leq 2\%.$
- 14. For design aid only, not subject to production testing.
 15. Switching characteristics are independent of operating junction temperatures.

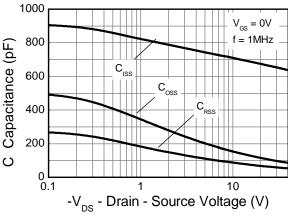


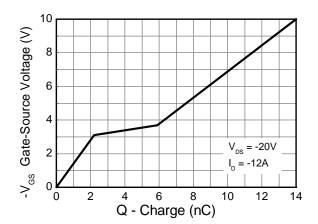
Typical Characteristics





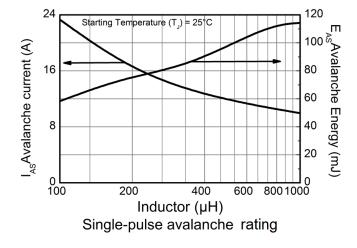
Typical Characteristics (Cont.)





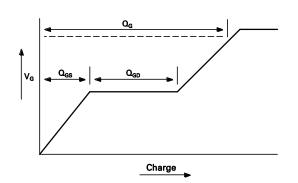
Capacitance v Drain-Source Voltage

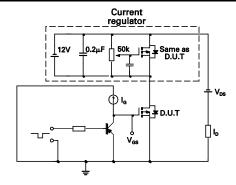
Gate-Source Voltage v Gate Charge





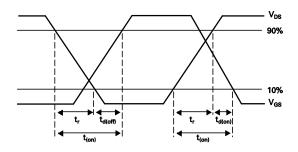
Test Circuits

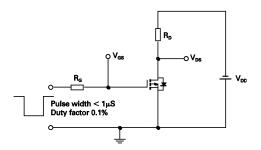




Basic gate charge waveform

Gate charge test circuit





Switching time waveforms

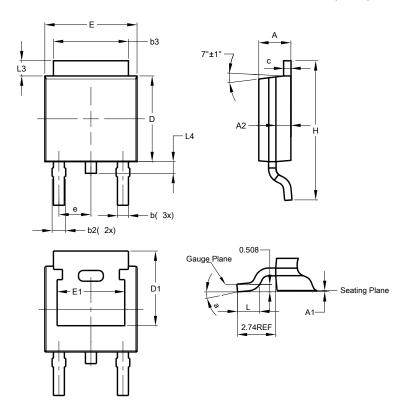
Switching time test circuit



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)

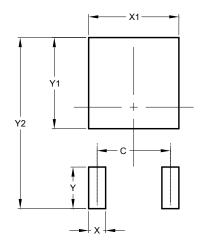


TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	i		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	-		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)



Dimensions	Value (in mm)		
С	4.572		
Х	1.060		
X1	5.632		
Υ	2.600		
Y1	5.700		
Y2	10.700		



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